

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

# 2SC2710

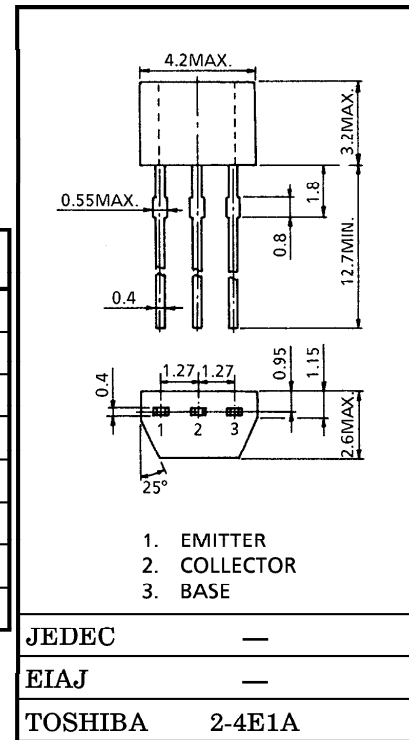
FOR AUDIO AMPLIFIER APPLICATIONS

Unit in mm

- High DC Current Gain :  $h_{FE}(1) = 100 \sim 320$
- Complementary to 2SA1150

**MAXIMUM RATINGS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CB0}$	35	V
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Base Voltage	$V_{EB0}$	5	V
Collector Current	$I_C$	800	mA
Base Current	$I_B$	160	mA
Collector Power Dissipation	$P_C$	300	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55~150	°C



**ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

Weight : 0.13g

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 35V, I_E = 0$	—	—	0.1	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = 5V, I_C = 0$	—	—	0.1	$\mu A$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10mA, I_B = 0$	30	—	—	V
DC Current Gain	$h_{FE}(1)$ (Note)	$V_{CE} = 1V, I_C = 100mA$	100	—	320	
	$h_{FE}(2)$	$V_{CE} = 1V, I_C = 700mA$	35	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 500mA, I_B = 20mA$	—	—	0.5	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE} = 1V, I_C = 10mA$	0.5	—	0.8	V
Transition Frequency	$f_T$	$V_{CE} = 5V, I_C = 10mA$	—	120	—	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	13	—	pF

Note :  $h_{FE}(1)$  Classification O : 100~200, Y : 160~320

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